PH1214-30EL

Technology Solutions

M/A-COM Products

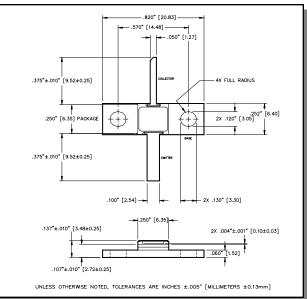
Released, 30 May 07

Radar Pulsed Power Transistor 30W, 1.2-1.4 GHz, 1ms Pulse, 10% Duty

Features

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- Diffused emitter ballasting resistors
- Gold metallization system
- · Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant

Outline Drawing



Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V _{CES}	56	V
Emitter-Base Voltage	V _{EBO}	3.0	V
Collector Current (Peak)	Ι _C	3.0	А
Power Dissipation @ +25°C	P _{TOT}	115	W
Storage Temperature	T _{STG}	-65 to +200	°C
Junction Temperature	TJ	200	°C

Electrical Specifications: T_c = 25 ± 5°C (Room Ambient)

Parameter	Test Conditions	Frequency	Symbol	Min	Мах	Units
Collector-Emitter Breakdown Voltage	I _C = 60mA		BV _{CES}	56	-	V
Collector-Emitter Leakage Current	V _{CE} = 28V		I _{CES}	-	3.0	mA
Thermal Resistance	Vcc = 28V, Pout = 30W	F = 1.2, 1.3, 1.4 GHz	R _{TH(JC)}	-	1.5	°C/W
Output Power	Vcc = 28V, Pout = 30W	F = 1.2, 1.3, 1.4 GHz	P _{IN}	-	4.9	W
Power Gain	Vcc = 28V, Pout = 30W	F = 1.2, 1.3, 1.4 GHz	G _P	7.8	-	dB
Collector Efficiency	Vcc = 28V, Pout = 30W	F = 1.2, 1.3, 1.4 GHz	η _c	50	-	%
Input Return Loss	Vcc = 28V, Pout = 30W	F = 1.2, 1.3, 1.4 GHz	RL	-	-10	dB
Load Mismatch Tolerance	Vcc = 28V, Pout = 30W	F = 1.2, 1.3, 1.4 GHz	VSWR-T	-	3:1	-
Load Mismatch Stability	Vcc = 28V, Pout = 30W	F = 1.2, 1.3, 1.4 GHz	VSWR-S	-	1.5:1	-

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are

Solutions has not average in the remaining source of the second s

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.

M/A-COM Technology Solutions Inc. and its affiliates reserve the right to make changes whe products) of in ormation contained herein without notice.

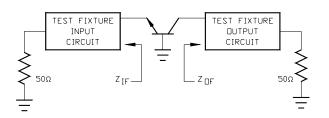


Radar Pulsed Power Transistor 30W, 1.2-1.4 GHz, 1ms Pulse, 10% Duty

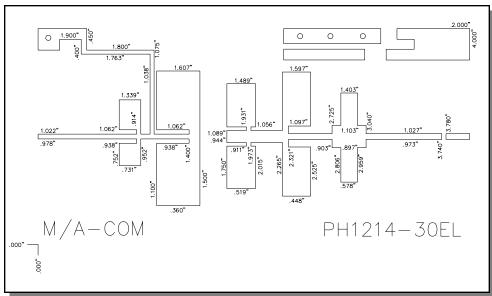
M/A-COM Products Released, 30 May 07

RF Test Fixture Impedance

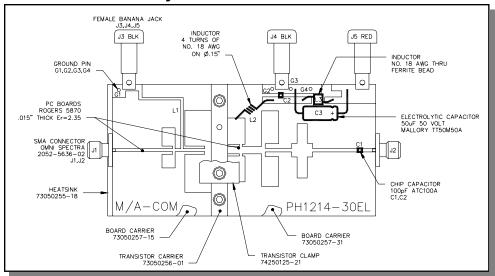
F (GHz)	Z _{IF} (Ω)	Ζ _{ΟF} (Ω)
1.2	2.5 - j3.5	10.5 + j2.0
1.3	2.7 - j2.7	6.3 + j2.0
1.4	3.5 - j3.5	5.3 + j1.5



Test Fixture Circuit Dimensions



Test Fixture Assembly



2 ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed. PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.

M/A-COM Technology Solutions Inc. and its affiliates reserve the right to make changes when products) by information contained herein without notice.